

Comparison of exact-exchange calculations for solids in current-spin-density- and spin-density-functional theory

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The relative merits of current-spin-density- and spin-density-functional theory are investigated for solids treated within the exact-exchange-only approximation. Spin-orbit splittings and orbital magnetic moments are determined at zero external magnetic field. We find that for magnetic (Fe, Co and Ni) and non-magnetic (Si and Ge) solids, the exact-exchange current-spin-density functional approach does not significantly improve the accuracy of the corresponding spin-density functional results.

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In the past 30 years, several generalizations of density functional theory (DFT) have been proposed. In the early 70's, DFT was extended to spin-DFT (SDFT) [1] by including the spin magnetization as basic quantity in addition to the density. This allows for coupling of the spin degrees of freedom to external magnetic fields and produces better results for spontaneously spin-polarized systems using approximate functionals. Adding yet another density, the paramagnetic current, leads to the framework of current-SDFT (CSDFT) [2, 3]. CSDFT includes the coupling of the external magnetic field, through its corresponding vector potential, to the orbital-degrees of freedom [3].

SDFT has been enormously successful in predicting the magnetic properties of materials. This success can be attributed to the availability of exchange correlation (xc) functionals which, even though originally designed for non-magnetic systems, could be systematically extended to the spin polarized case. The most popular of these functionals are the local spin density approximation (LSDA) and the generalized gradient approximation (GGA). CSDFT, on the other hand, has not enjoyed the same attention mainly because of problems which arise in the extension of LSDA and GGA to include the paramagnetic current density [4]. Exposing the homogeneous electron gas to an external magnetic field leads to the appearance of Landau levels which, in turn, give rise to derivative discontinuities in the resulting xc energy density. Using this quantity to construct (semi-)local functionals then automatically leads to local discontinuities in the corresponding xc potentials, which are then awkward to use in practical calculations.

Such problems can be avoided with the use of or-

bitals functionals and this fact, coupled with the success of these functionals for SDFT calculations, has led to recent interest in orbital functionals for CSDFT [5–9]. The results from these works have shown mixed success. A modified version of the original CSDFT [10] lead to promising results for spin-orbit induced splittings of bands in solids, such as Si and Ge [7]. In contrast it was found that for open-shell atoms and quantum dots the difference between SDFT and CSDFT results was minimal [5, 6]. Similarly, calculations for solids using a local vorticity functional [11] and for quantum dots using a LSDA-type xc functional [12] could not establish the superiority of CSDFT over SDFT.

In this work we present a systematic comparison of the relative merits of CSDFT and SDFT for solids. Since the Kohn-Sham (KS) system in CSDFT reproduces the current of the interacting system, one would expect differences between SDFT and CSDFT results for orbital magnetic moments (which can be directly derived from the current). With this in mind we calculate the orbital magnetic moment of the spontaneous magnets Fe, Co and Ni. Since CSDFT is believed to improve the spin-orbit induced band splitting in the non-magnetic semiconductors Si and Ge [7] it makes these materials interesting candidates for a study of the differences between the two approaches.

Following Vignale and Rasolt [2, 3], the ground state energy of a (non-relativistic) system of interacting electrons in the presence of an external magnetic field $\mathbf{B}_0(\mathbf{r}) = \nabla \times \mathbf{A}_0(\mathbf{r})$ can be written as functional of the particle density $\rho(\mathbf{r})$, the magnetization density $\mathbf{m}(\mathbf{r})$ and the paramagnetic current density $\mathbf{j}_p(\mathbf{r})$. This functional is given by

$$E[\rho, \mathbf{m}, \mathbf{j}_p] = T_s[\rho, \mathbf{m}, \mathbf{j}_p] + U[\rho] + E_{xc}[\rho, \mathbf{m}, \mathbf{j}_p] + \int \rho(\mathbf{r}) v_0(\mathbf{r}) d\mathbf{r} \quad (1)$$

$$- \int \mathbf{m}(\mathbf{r}) \cdot \mathbf{B}_0(\mathbf{r}) d\mathbf{r} + \frac{1}{c} \int \mathbf{j}_p(\mathbf{r}) \cdot \mathbf{A}_0(\mathbf{r}) d\mathbf{r} + \frac{1}{2c^2} \int \rho(\mathbf{r}) \mathbf{A}_0^2(\mathbf{r}) d\mathbf{r},$$

where $T_s[\rho, \mathbf{m}, \mathbf{j}_p]$ is the kinetic energy functional of non-interacting electrons, $U[\rho]$ is the Hartree energy, and $E_{xc}[\rho, \mathbf{m}, \mathbf{j}_p]$ is the exchange-correlation energy. Minimization of Eq. (1) with respect to the three basic densities leads to the Kohn-Sham (KS) equation which reads

$$\left[\frac{1}{2} \left(i\nabla + \frac{1}{c} \mathbf{A}_s(\mathbf{r}) \right)^2 + v_s(\mathbf{r}) + \mu_B \boldsymbol{\sigma} \cdot \mathbf{B}_s(\mathbf{r}) \right] \Phi_i(\mathbf{r}) = \varepsilon_i \Phi_i(\mathbf{r}). \quad (2)$$

Here $\boldsymbol{\sigma}$ is the vector of Pauli matrices and the Φ_i are spinor valued wave functions. The effective potentials $v_s(\mathbf{r})$, $\mathbf{B}_s(\mathbf{r})$ and $\mathbf{A}_s(\mathbf{r})$ are such that the ground-state densities $\rho(\mathbf{r})$, $\mathbf{m}(\mathbf{r})$ and $\mathbf{j}_p(\mathbf{r})$ of the interacting system are reproduced. These effective potentials are given by

$$v_s(\mathbf{r}) = v_0(\mathbf{r}) + v_H(\mathbf{r}) + v_{xc}(\mathbf{r}) + \frac{1}{2c^2} (\mathbf{A}_0^2(\mathbf{r}) - \mathbf{A}_s^2(\mathbf{r})), \quad \mathbf{B}_s(\mathbf{r}) = \mathbf{B}_0(\mathbf{r}) + \mathbf{B}_{xc}(\mathbf{r}), \quad \mathbf{A}_s(\mathbf{r}) = \mathbf{A}_0(\mathbf{r}) + \mathbf{A}_{xc}(\mathbf{r}). \quad (3)$$

Here, $v_0(\mathbf{r})$ is the external electrostatic potential and $v_H(\mathbf{r}) = \int \rho(\mathbf{r}')/|\mathbf{r} - \mathbf{r}'| d^3r'$ is the Hartree potential. The xc potentials are given as functional derivatives of the xc energy with respect to the corresponding conjugate densities which can be obtained from KS wave functions using the following relations

$$\rho(\mathbf{r}) = \sum_{i=1}^{\text{occ}} \Phi_i^\dagger(\mathbf{r}) \Phi_i(\mathbf{r}), \quad \mathbf{m}(\mathbf{r}) = -\mu_B \sum_{i=1}^{\text{occ}} \Phi_i^\dagger(\mathbf{r}) \boldsymbol{\sigma} \Phi_i(\mathbf{r}), \quad \mathbf{j}_p(\mathbf{r}) = \frac{1}{2i} \sum_{i=1}^{\text{occ}} \left\{ \Phi_i^\dagger(\mathbf{r}) \nabla \Phi_i(\mathbf{r}) - [\nabla \Phi_i^\dagger(\mathbf{r})] \Phi_i(\mathbf{r}) \right\} \quad (4)$$

where the sum runs over the occupied orbitals. For practical calculations, an approximation for the xc energy functional $E_{xc}[\rho, \mathbf{m}, \mathbf{j}_p]$ has to be adopted. Here we concentrate on approximations of the xc functional which explicitly depend on the KS orbitals and therefore only implicitly on the densities. Such orbital functionals are usually treated within the framework of the so-called Optimized Effective Potential (OEP) method [13–15] where, the xc potential is obtained as solution of the OEP integral equation. Recently, the OEP method has been generalized to non-collinear SDFT [16] and CSDFT [5, 6]. Another generalization of the OEP method in the context of a spin-current DFT (SCDFT) based on a different choice of densities has also been put forward [9]. In the present work the formalism of Refs. (5) and (6) is used and the corresponding OEP equations can be put in a compact form as

$$\sum_{k=1}^{\text{occ}} \Phi_k^\dagger(\mathbf{r}) \Psi_k(\mathbf{r}) + h.c. = 0, \quad -\mu_B \sum_{k=1}^{\text{occ}} \Phi_k^\dagger(\mathbf{r}) \boldsymbol{\sigma} \Psi_k(\mathbf{r}) + h.c. = 0, \quad \frac{1}{2i} \sum_{k=1}^{\text{occ}} \left\{ \Phi_k^\dagger(\mathbf{r}) \nabla \Psi_k(\mathbf{r}) - [\nabla \Phi_k^\dagger(\mathbf{r})] \Psi_k(\mathbf{r}) \right\} + h.c. = 0, \quad (5)$$

where the so-called orbital shifts [15, 17] are defined as $\Psi_k(\mathbf{r}) = \sum_j^{\text{unocc}} \frac{\Phi_j(\mathbf{r}) \Lambda_{kj}}{\varepsilon_k - \varepsilon_j}$, here the summation runs over the unoccupied states and

$$\Lambda_{kj} = \int d^3r' \left(v_{xc}(\mathbf{r}') \rho_{kj}(\mathbf{r}') + \frac{1}{c} \mathbf{A}_{xc}(\mathbf{r}') \mathbf{j}_{p_{kj}}(\mathbf{r}') - \mathbf{B}_{xc}(\mathbf{r}') \mathbf{m}_{kj}(\mathbf{r}') - \Phi_j^\dagger(\mathbf{r}') \frac{\delta E_{xc}}{\delta \Phi_k^\dagger(\mathbf{r}')} \right) \quad (6)$$

where $\rho_{kj}(\mathbf{r}) = \Phi_j^\dagger(\mathbf{r}) \Phi_k(\mathbf{r})$, $\mathbf{m}_{kj}(\mathbf{r}) = -\mu_B \Phi_j^\dagger(\mathbf{r}) \boldsymbol{\sigma} \Phi_k(\mathbf{r})$ and $\mathbf{j}_{p_{kj}}(\mathbf{r}) = \frac{1}{2i} \left\{ \Phi_j^\dagger(\mathbf{r}) \nabla \Phi_k(\mathbf{r}) - [\nabla \Phi_j^\dagger(\mathbf{r})] \Phi_k(\mathbf{r}) \right\}$.

Eq. (5) has a structure very similar to the OEP equations for non-collinear SDFT differing only by the redefinition of the matrix Λ , which now also contains an extra term depending upon the current density and its conjugate field. Due to their similar structure the CSDFT OEP equations are solved by generalizing the "residue algorithm", successfully applied to solve the non-collinear

SDFT equations [16–18]. The only difference in the case of CSDFT is introduction of an additional residue coming from the third OEP equation in Eq. (5). In the present work we have used the exchange-only exact-exchange (EXX) functional to solve the OEP equations. The EXX energy functional is the Fock exchange energy but eval-

uated with KS spinors

$$E_x^{\text{EXX}}[\{\Phi_i\}] \equiv -\frac{1}{2} \int \int \sum_{i,j}^{\text{occ}} \frac{\Phi_i^\dagger(\mathbf{r})\Phi_j(\mathbf{r})\Phi_j^\dagger(\mathbf{r}')\Phi_i(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}'. \quad (7)$$

In order to keep the numerical analysis as accurate as possible, in the present work all calculations are performed using the state-of-the-art full-potential linearized augmented plane wave (FPLAPW) method [19], implemented within the EXCITING code [20]. The single-electron problem is solved using an augmented plane wave basis without using any shape approximation for the effective potential. Likewise, the magnetization and current densities and their conjugate fields are all treated as unconstrained vector fields throughout space. The deep lying core states (3 Ha below the Fermi level) are treated as Dirac spinors and valence states as Pauli spinors. To obtain the Pauli spinor states, the Hamiltonian containing only the scalar fields is diagonalized in the LAPW basis: this is the first-variational step. The scalar states thus obtained are then used as a basis to set up a second-variational Hamiltonian with spinor degrees of freedom, which consists of the first-variational eigenvalues along the diagonal, and the matrix elements obtained from the external and effective vector fields in Eq. (2). This is more efficient than simply using spinor LAPW functions, but care must be taken to ensure there are a sufficient number of first-variational eigenstates for convergence of the second-variational problem. Spin-orbit coupling is also included at this stage.

As was shown above for CSDFT, the magnetic field couples not only to spin but also to the orbital degrees of freedom through the vector potential. This makes CSDFT specifically important for magnetic materials and particularly interesting for their orbital properties. By analogy with SDFT, one might expect that the introduction of the paramagnetic current density gives an improvement in properties such as orbital moments and spin-orbit induced band splitting, which are related to this new basic variable. However, within the framework of existing functionals it is yet to be established conclusively that CSDFT performs better than SDFT for these properties. The recent development of the OEP method both for SDFT and CSDFT allows for a direct comparison of these two approaches for the same xc functional, namely EXX.

The orbital moments for spontaneous magnets Fe, Co and Ni, in the absence of external magnetic fields and with spin-orbit coupling included, are presented in Table I. For SDFT, the LSDA, GGA and EXX functionals are used, while for CSDFT the values are obtained using the EXX functional. It is clear from Table I that there is *no difference* between the results obtained using EXX-CSDFT and EXX-SDFT. It should also be noted that in comparison to experiments the EXX results are significantly worse than their LSDA and GGA counterparts.

Solid	Exp.	SDFT			CSDFT
		LSDA	GGA	EXX	EXX
Fe	0.08	0.053	0.051	0.034	0.034
Co	0.14	0.069	0.073	0.013	0.013
Ni	0.05	0.038	0.037	0.029	0.029
		36.2	36.7	63.4	63.4

TABLE I: Orbital magnetic moments for bulk Fe, Co and Ni in μ_B . The experimental data are taken from Ref. (21). The final row lists the average percentage deviation of the numerical results from the experimental value.

Symmetry point	Exp.	SDFT			CSDFT	
		LSDA	GGA	EXX	EXX ^p	EXX ^o
Ge Γ_{7v-8v}	297	311	296	291.3	289	258.1
Ge Γ_{6c-8c}	200	229.7	220	201.3	199	173.3
Si Γ_{25v}	44	50	58	42.5	45.5	42.5
		9.5	14.0	2.0	2.2	10.5

TABLE II: Spin-orbit induced splittings for bulk Ge and Si in meV. The experimental data is taken from Ref. (23). EXX^p are results of the present work and EXX^o are results from Ref. (7). The final row lists the average percentage deviation of numerical results from the experimental value.

One reason, of course, is the fact that LSDA and GGA also include correlation in an approximate way which is neglected completely within the EXX framework.

In a recent work [7] it is shown that the use of the EXX functional in the framework of CSDFT, improves the spin-orbit induced splitting of the bands in semiconductors. Unfortunately, it is not clear if this improvement is due to the use of different functionals (going from LSDA to EXX), or due to the use of an extra density when going from SDFT to CSDFT. This has motivated us to compare CSDFT and SDFT results for this quantity using the same functional in both cases. We have determined the value of this splitting for solid Si and Ge and the results are presented in Table II. While the EXX functional significantly improves the agreement with experimental values, there is almost no change on going from SDFT to CSDFT. Thus the improvement is solely due to the orbital based functional. We also note that the EXX-CSDFT results of Ref. (7) are significantly different from ours, and in much worse agreement with experiments. This might be due to the use of pseudopotentials in the previous work. In this respect it is worth noting that EXX derived KS energy gaps also show significant differences depending on whether an all-electron full-potential or pseudopotential method is used [22].

In order to probe why, upon going from SDFT to CSDFT, we have found almost no difference in either the orbital moments or spin-orbit induced band splittings, it is instructive to plot the paramagnetic current density. This is shown in Fig. (1) for the case of Ge. \mathbf{j}_p is de-

terminated using the KS orbitals obtained at the end of the self-consistent procedure in LSDA, GGA and EXX-SDFT calculations. We have chosen Ge as an example since the spin-orbit induced splitting is largest for this system and, unlike in the case of orbital moments, this quantity does show some difference on going from SDFT to CSDFT. The most noticeable feature in Fig.(1) is the fact that the value of the current is much smaller in the case of EXX-SDFT and CSDFT as compared to their LSDA/GGA counterparts. This is an interesting finding since it indicates the tendency of (semi-) local functionals towards higher values of the paramagnetic current density. This is also in line with the previous results: for open-shell atoms in the absence of any external magnetic field it was found [5] that EXX-CSDFT leads to ground states with vanishing current.

Even though \mathbf{j}_p significantly differs in magnitude and structure in EXX-SDFT and CSDFT, the observables depending on it are almost the same. Similar conclusions were also drawn for quantum dots in external magnetic fields studied using EXX [6] and other functionals of the current density [12]. From Fig. (1) it is clear that one of the major effect of including \mathbf{j}_p as a basic variable within the OEP method is to change its structure, which in turn suggests that quantities depending on local properties of the currents, such as chemical shifts, might exhibit larger differences in the two approaches. Such calculations [24] of chemical shifts, performed using *local* functionals, found that for molecules this is not the case. The effect of the EXX functional on these shifts could be an interesting subject for future investigations.

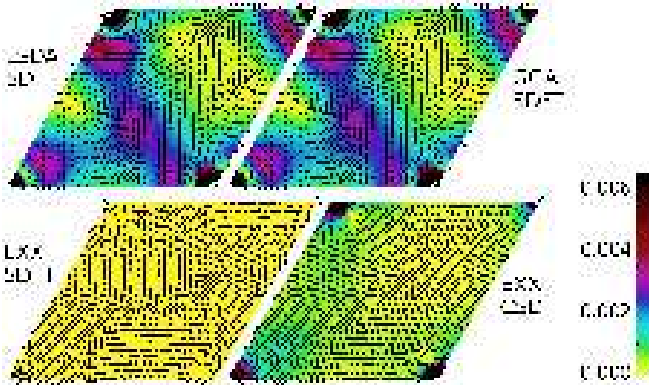


FIG. 1: Paramagnetic current density for Ge calculated using the SDFT and CSDFT. Arrows indicate the direction and information about the magnitude is given in the colour bar.

To summarize, in this work we have presented EXX-SDFT and CSDFT calculations for solids. The orbital magnetic moments of Fe, Co and Ni and the spin-orbit induced band splitting of Si and Ge are computed. Our analysis shows only minor differences between EXX-CSDFT and SDFT results. The spin-orbit induced band splittings in EXX calculations are in rather good agree-

ment with experiments, while the results for the orbital moments are worse than the LSDA or GGA values. This highlights the importance of proper treatment of correlations for the accurate determination of the orbital moments.

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